CHENMKO ENTERPRISE CO.,LTD

CHUMG6PT

SURFACE MOUNT
Dual Digital Silicon Transistor

VOLTAGE 50 Volts CURRENT 100 mAmpere

Lead free devices

APPLICATION

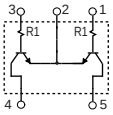
* Switching circuit, Inverter, Interface circuit, Driver circuit.

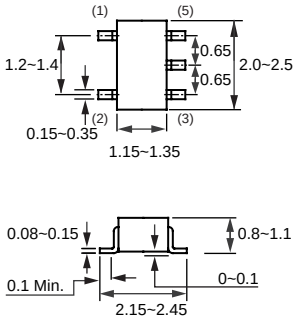
FEATURE

* Small surface mounting type. (SC-88A/SOT-353)
* High current gain.
* Suitable for high packing density.
* Low colloector-emitter saturation.
* High saturation current capability.
* Both the CHDTC144T in one package.
* Built in bias resistor(R1=47kΩ, Typ.)

SC-88A/SOT353

CIRCUIT





Dimensions in millimeters

SC-88A/SOT353

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-Base voltage		50	V
V_{CEO}	Collector-Emitter voltage		50	V
V_{EBO}	Emitter-Base voltage		5	V
$I_{C(Max.)}$	Collector current		100	mA
P_D	Power dissipation	$T_{amb} \leq 25\ ^{\circ}C$, Note 1	150	mW
T_{STG}	Storage temperature		−55 +150	$^{\circ}C$
T_J	Junction temperature		−55 +150	$^{\circ}C$
$R\theta_{J-S}$	Thermal resistance , Note 1	junction - soldering point	140	$^{\circ}C/W$

Note

1. Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC (CHUMG6PT)

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise speciÞed.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
BV_{CBO}	Collector-base breakdown voltage	I_C=50uA	50	–	–	V
BV_{CEO}	Collector-emitter breakdown voltage	I_C=1.0mA	50	–	–	V
BV_{EBO}	Emitter-base breakdown voltage	I_E=50uA	5.0	–	–	V
I_{CBO}	Collector cutoff current	V_{CB}=50V	–	–	0.5	uA
I_{EBO}	Emitter cutoff current	V_{EB}=4V	–	–	0.5	uA
$V_{CE(sat)}$	Collector-emitter saturation voltage	I_C/I_B=5mA/0.5mA	–	–	0.3	V
h_{FE}	DC current gain	I_C=1mA; V_{CE}=5.0V	100	250	600	
R_1	Input resistor		32.9	47	61.1	KΩ
f_T	Transition frequency	I_C=5mA, V_{CE}=10.0V *f*=100MHz	–	250	–	MHz

Note

1.Pulse test: tp≤300uS; δ≤0.02.

RATING CHARACTERISTIC CURVES (CHUMG6PT)

Typical Electrical Characteristics

Fig.1 DC current gain vs. collector current

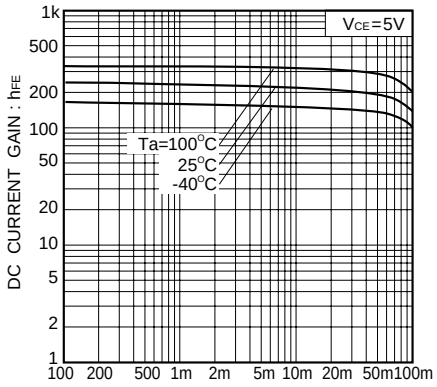


Fig.2 Collector-emitter voltage vs. collector current